

TOSHIBA

TA78M05,06,08,09,10,12,15,18,20,24S

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

**TA78M05S, TA78M06S, TA78M08S, TA78M09S, TA78M10S
TA78M12S, TA78M15S, TA78M18S, TA78M20S, TA78M24S**

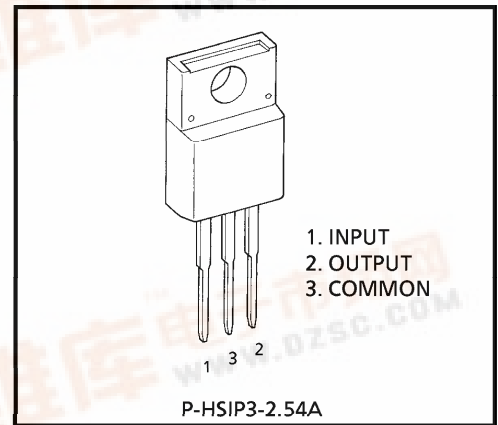
0.5 A THREE TERMINAL POSITIVE VOLTAGE REGULATORS

5 V, 6 V, 8 V, 9 V, 10 V, 12 V, 15 V, 18 V, 20 V, 24 V

The TA78M × S series of fixed-voltage monolithic integrated circuit voltage regulators is designed for a wide range of applications. These regulators employ internal current-limiting, thermal-shutdown and safe-area compensation, making them essentially indestructible. One of these regulators can driver up to 0.5 A of output current.

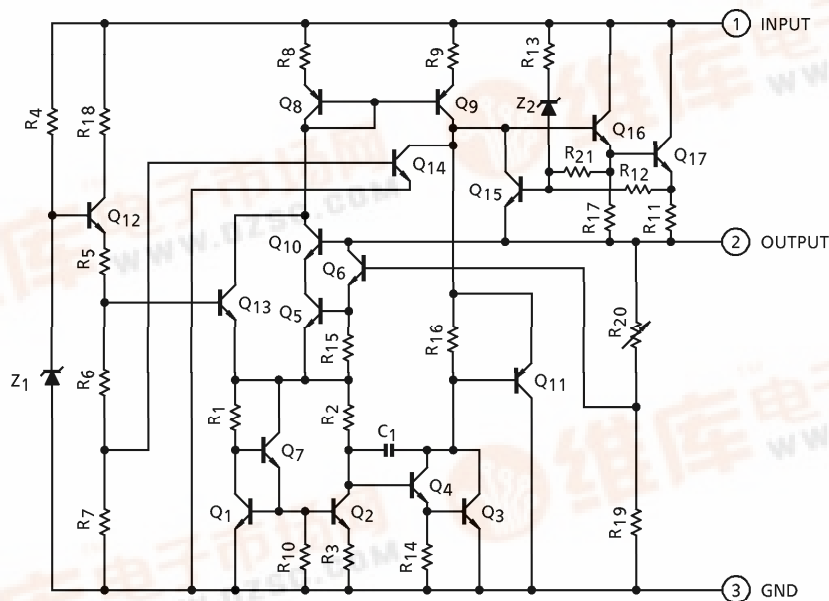
FEATURES

- Suitable for CMOS, TTL and the other Digital IC's Power Supply.
- Output Current in Excess of 0.5 A
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Package in the Plastic Case TO-220NIS



Weight : 1.7 g (Typ.)

EQUIVALENT CIRCUIT



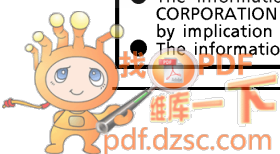
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● The information contained herein is subject to change without notice.



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Input Voltage	TA78M05S	VIN	35	V
	TA78M06S			
	TA78M08S			
	TA78M09S			
	TA78M10S			
	TA78M12S			
	TA78M15S			
	TA78M18S			
	TA78M20S		40	
	TA78M24S			
Power Dissipation	(Ta = 25°C)	PD	2	W
	(Tc = 25°C)		20	
Operating Temperature		Topr	- 30~85	°C
Storage Temperature		Tstg	- 55~150	°C
Junction Temperature		Tj	150	°C
Thermal Resistance		Rth(j-c)	6.25	°C/W
		Rth(j-a)	62.5	

TA78M05S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 10\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	4.8	5.0	5.2	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$7\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	100	mV	
				$8\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	2	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	25	100	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	50		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	4.75	—	5.25	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.5	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	$8.5\text{ V} \leq V_{IN} \leq 25.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	50	200	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $8\text{ V} \leq V_{IN} \leq 18\text{ V}$, $T_j = 25^\circ\text{C}$	62	69	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-0.6	—	$\text{mV}/^\circ\text{C}$		

TA78M06S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 11\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	5.75	6.0	6.25	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$8\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	100	mV	
				$9\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	2	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	25	120	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	60		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	5.7	—	6.3	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.5	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	9.5 V \leq V_{IN} \leq 25.5 V, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	5 mA \leq I_{OUT} \leq 350 mA	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, 10 Hz \leq f \leq 100 kHz	—	55	220	μV_{rms}		
Ripple Rejection	R.R.	3	f = 120 Hz, $I_{OUT} = 100\text{ mA}$ 9 V \leq V_{IN} \leq 19 V, $T_j = 25^\circ\text{C}$	59	66	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-0.7	—	mV / $^\circ\text{C}$		

TA78M08S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 14V$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	7.7	8.0	8.3	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$10.5\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	5	100	mV	
				$11\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	26	160	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	80		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	7.6	—	8.4	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.6	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	11 V \leq V_{IN} \leq 25.5 V, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	5 mA \leq I_{OUT} \leq 350 mA	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, 10 Hz \leq f \leq 100 kHz	—	60	250	μV_{rms}		
Ripple Rejection	R.R.	3	f = 120 Hz, $I_{OUT} = 100\text{ mA}$ 11.5 V \leq V_{IN} \leq 21.5 V, $T_j = 25^\circ\text{C}$	56	63	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.0	—	mV / $^\circ\text{C}$		

TA78M09S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 15\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	8.64	9.0	9.36	V	
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$11.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	5	100	mV
				$13\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	26	180	mV
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	90	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	8.55	—	9.45	V	
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.6	8.0	mA	
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	—	—	0.8	mA
	Load	ΔI_{BO}						
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	60	270	μV_{rms}	
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $12.5\text{ V} \leq V_{IN} \leq 22.5\text{ V}$, $T_j = 25^\circ\text{C}$	56	63	—	dB	
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA	
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V	
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.1	—	$\text{mV}/^\circ\text{C}$	

TA78M10S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 16\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	9.6	10.0	10.4	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$12.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	6	100	mV	
				$14\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	26	200	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	100		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	9.5	—	10.5	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.7	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	13 V \leq V_{IN} \leq 26.5 V, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	65	280	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $13.5\text{ V} \leq V_{IN} \leq 23.5\text{ V}$, $T_j = 25^\circ\text{C}$	55	62	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.3	—	$\text{mV}/^\circ\text{C}$		

TA78M12S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 19\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	11.5	12.0	12.5	V	
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$14.5\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	7	100	mV
				$16\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	27	240	mV
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	120	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	11.4	—	12.6	V	
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.8	8.0	mA	
Quiescent Current Change	Line	1	$T_j = 25^\circ\text{C}$	$15\text{ V} \leq V_{IN} \leq 30.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load			$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	—	0.5	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	70	300	μV_{rms}	
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $15\text{ V} \leq V_{IN} \leq 25\text{ V}$, $T_j = 25^\circ\text{C}$	55	62	—	dB	
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA	
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V	
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.6	—	$\text{mV}/^\circ\text{C}$	

TA78M15S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 23\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	14.4	15.0	15.6	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$17.5\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	8	100	mV	
				$20\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	27	300	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	150		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	14.25	—	15.75	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.8	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	$18\text{ V} \leq V_{IN} \leq 30.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	80	450	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $18.5\text{ V} \leq V_{IN} \leq 28.5\text{ V}$, $T_j = 25^\circ\text{C}$	54	61	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-2.0	—	$\text{mV}/^\circ\text{C}$		

TA78M18S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 27\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	17.3	18.0	18.7	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$21\text{ V} \leq V_{IN} \leq 33\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	9	100	mV	
				$24\text{ V} \leq V_{IN} \leq 33\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	5	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	28	360	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	180		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	17.1	—	18.9	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.8	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	$21.5\text{ V} \leq V_{IN} \leq 33.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	90	490	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $22\text{ V} \leq V_{IN} \leq 32\text{ V}$, $T_j = 25^\circ\text{C}$	53	60	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-2.5	—	$\text{mV}/^\circ\text{C}$		

TA78M20S

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 29\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	19.2	20.0	20.8	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$23\text{ V} \leq V_{IN} \leq 35\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	10	100	mV	
				$24\text{ V} \leq V_{IN} \leq 35\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	6	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	28	400	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	200		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	19.0	—	21.0	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.9	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	23.5 V \leq V_{IN} \leq 35.5 V, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	95	540	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $24\text{ V} \leq V_{IN} \leq 34\text{ V}$, $T_j = 25^\circ\text{C}$	53	60	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-3.0	—	$\text{mV}/^\circ\text{C}$		

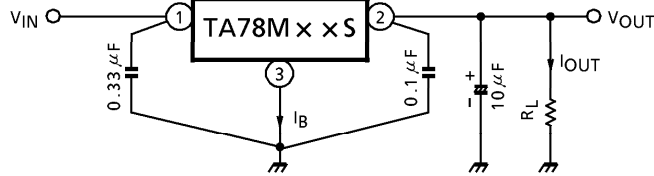
TA78M24S

ELECTRICAL CHARACTERISTICS

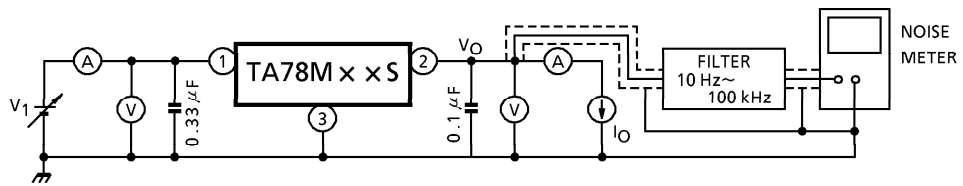
(Unless otherwise specified, $V_{IN} = 33\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	23.0	24.0	25.0	V		
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$27\text{ V} \leq V_{IN} \leq 38\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	12	100	mV	
				$28\text{ V} \leq V_{IN} \leq 38\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	7	50		
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	30	480	mV	
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	240		
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	22.8	—	25.2	V		
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	5.0	8.0	mA		
Quiescent Current Change	Line	ΔI_B	1	$T_j = 25^\circ\text{C}$	27.5 V \leq V_{IN} \leq 38.5 V, $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}				1	$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	115	650	μV_{rms}		
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $28\text{ V} \leq V_{IN} \leq 38\text{ V}$, $T_j = 25^\circ\text{C}$	50	57	—	dB		
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA		
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V		
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-3.5	—	$\text{mV}/^\circ\text{C}$		

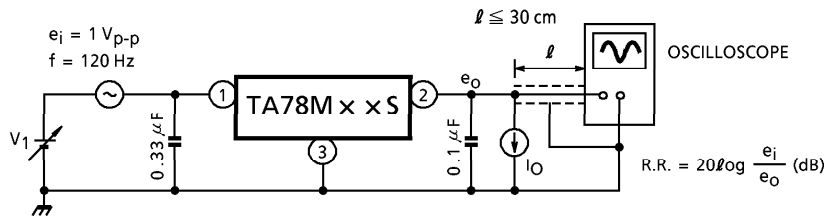
TEST CIRCUIT 1 / STANDARD APPLICATION

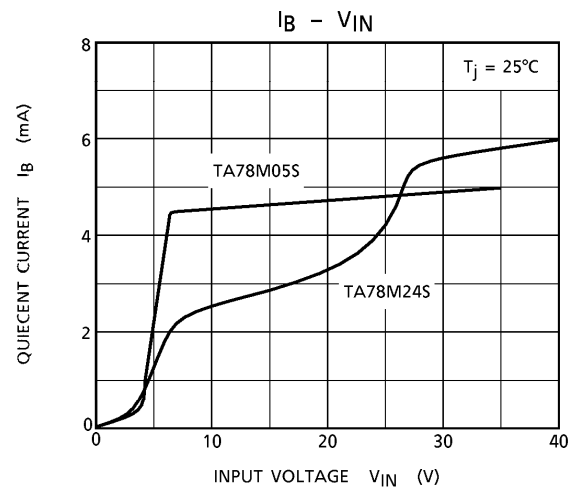
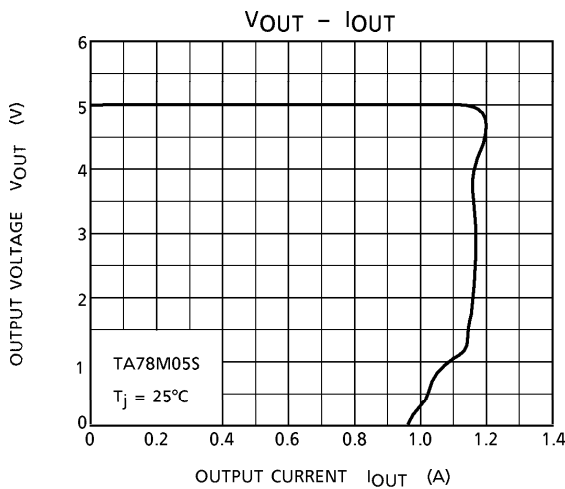
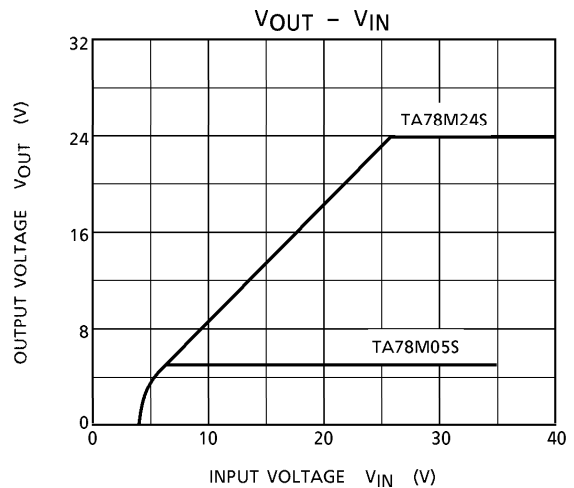
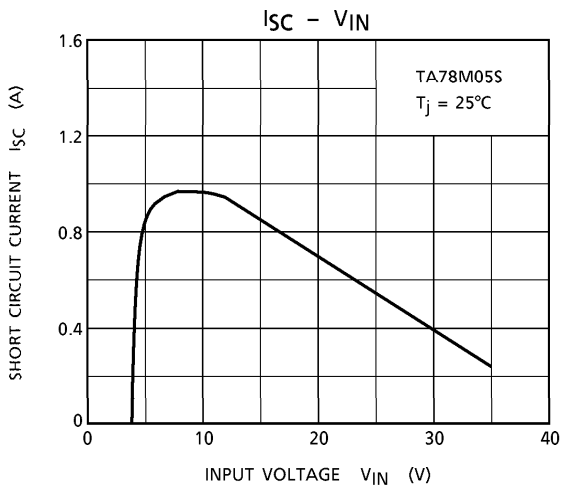
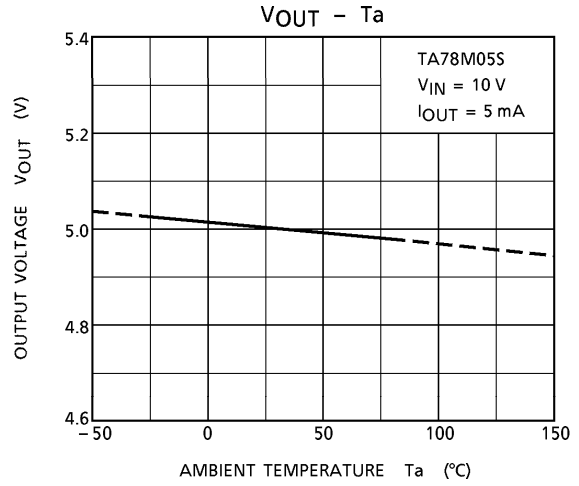
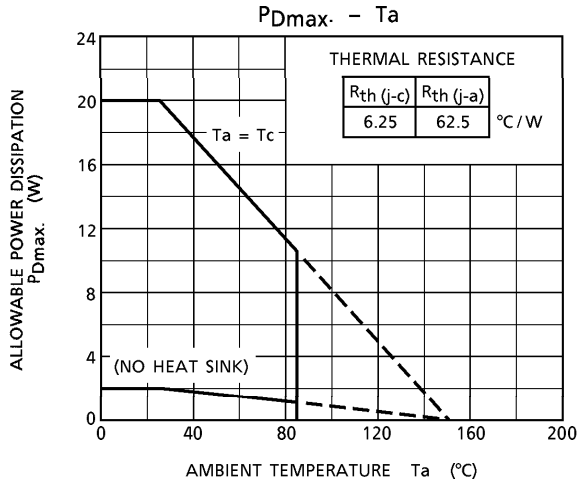


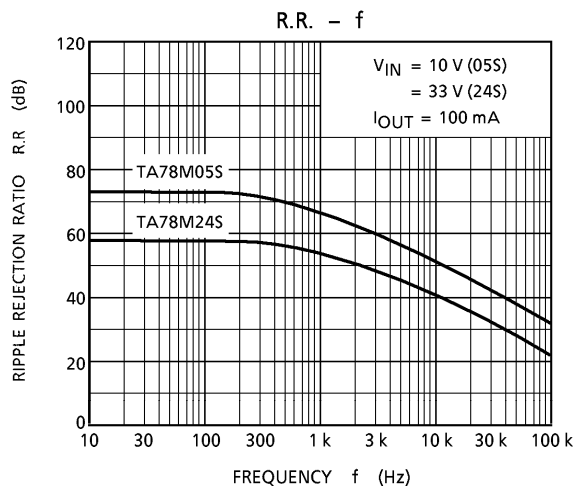
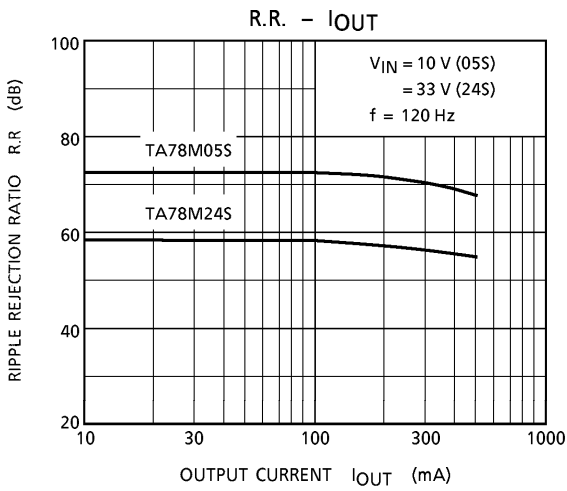
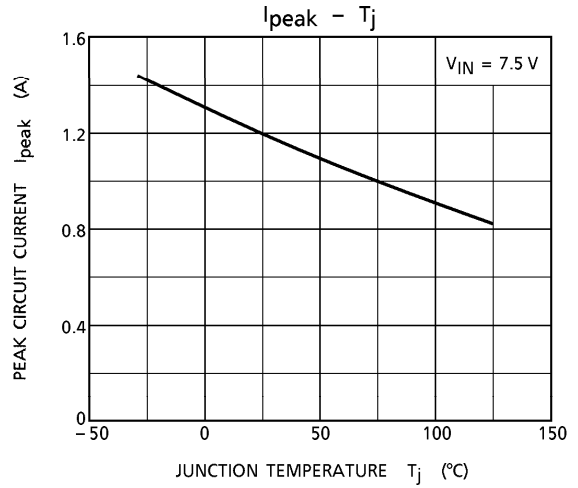
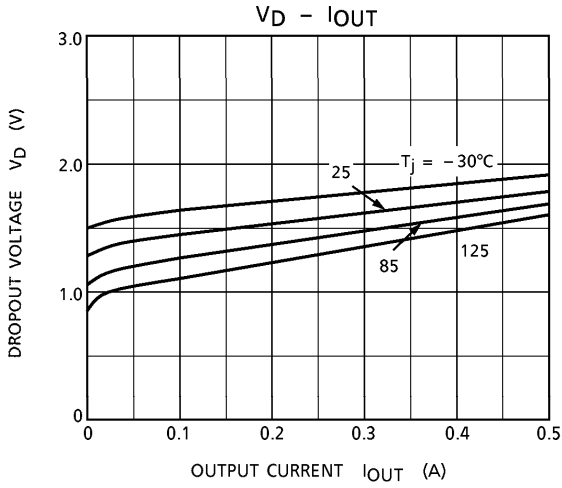
TEST CIRCUIT 2 V_{NO}



TEST CIRCUIT 3 R.R.







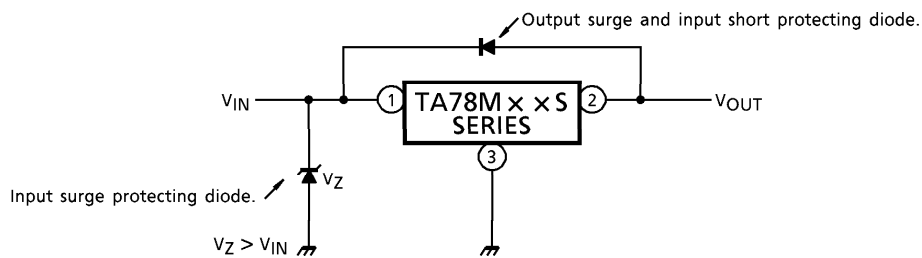
PRECAUTIONS ON APPLICATION

- (1) In regard to GND, be careful not to apply a negative voltage to the input/output terminal. Further, special care is necessary in case of a voltage boost application.
- (2) When a surge voltage exceeding maximum rating is applied to the input terminal or when a voltage in excess of the input terminal voltage is applied to the output terminal, the circuit may be destroyed.

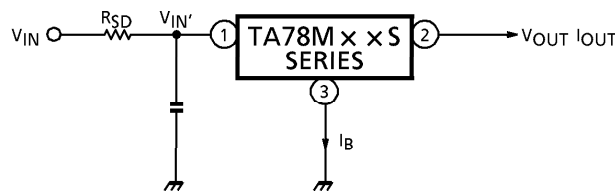
Specially, in the latter case, great care is necessary.

Further, if the input terminal sorts to GND in a state of normal operation, the output terminal voltage becomes higher than the input voltage (GND potential), and the electric charge of a chemical capacitor connected to the output terminal flows into the input side, which may cause the destruction of circuit.

In these cases, take such steps as a zener diode and a general silicon diode are connected to the circuit, as shown in the following figure.



- (3) When the input voltage is too high, the power dissipation of three terminal regulator increases because of series regulator, so that the junction temperature rises. In such a case, it is recommended to reduce the power dissipation by inserting the power limiting resistor R_{SD} in the input terminal, and to reduce the junction temperature as a result.



The power dissipation P_D of IC is expressed in the following equation.

$$P_D = (V_{IN'} - V_{OUT}) \cdot I_{OUT} + V_{IN'} \cdot I_B$$

If V_{IN}' is reduced below the lowest voltage necessary for the IC, the parasitic oscillation will be caused according to circumstances.

In determining the resistance value of R_{SD}, design with margin should be made by making reference to the following equation.

$$R_{SD} < \frac{V_{IN} - V_{IN'}}{I_{OUT} + I_B}$$

- (4) Connect the input terminal and GND, and the output terminal and GND, by capacitor respectively. The capacitances should be determined experimentally because they depend on printed patterns. In particular, adequate investigation should be made so that there is no problem even at time of high or low temperature.
- (5) Installation of IC for power supply
 For obtaining high reliability on the heat sink design of the regulator IC, it is generally required to derate more than 20% of maximum junction temperature (T_j MAX.).
 Further, full consideration should be given to the installation of IC to the heat sink.

(a) Heat sink design

The thermal resistance of IC itself is required from the viewpoint of the design of elements, but the thermal resistance from the IC package to the open air varies with the contact thermal resistance.

Table 1 shows how much the value of the contact thermal resistance ($\theta_c + \theta_s$) is changed by heat sink grease.

TABLE 1

Unit : °C/W

PACKAGE	MODEL No.	TORQUE	MICA	$\theta_c + \theta_s$
TO-220NIS	TA78M × × S	0.6 N·m	Not Provided	0.3~0.5 (1.5~2.0)

The figures given in parentheses denote the values at time of no grease.

(b) Silicon grease

When a circuit not exceeding maximum rating is designed, it is to be desired that the grease should be used if possible. If it is required that the contact thermal resistance is reduced from the viewpoint of the circuit design, it is recommended that the following methods be adopted.

A : Use YG6260 (TOSHIBA SILICON CORPORATION), if grease is used.

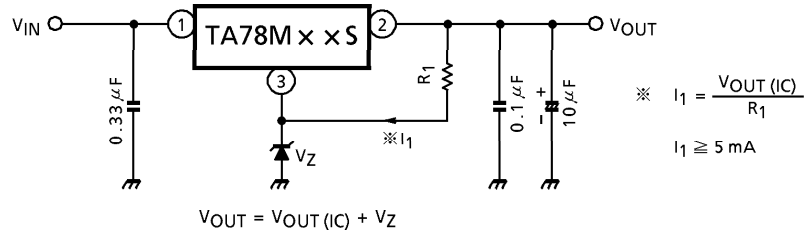
(c) Torque

When installing IC on a heat sink or the like, tighten the IC with the torque of less than the rated value. If it is tightened with the torque in excess of the rated value, sometimes the internal elements of the IC are adversely affected. Therefore, great care should be given to the installing operation.

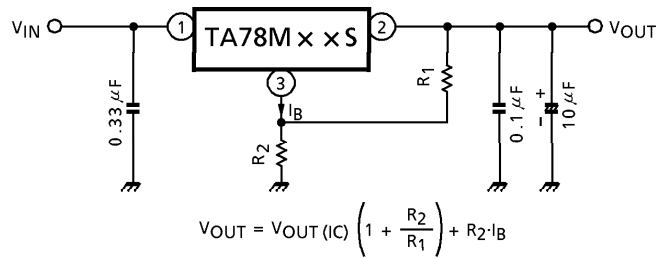
APPLICATION CIRCUITS

(1) VOLTAGE BOOST REGULATOR

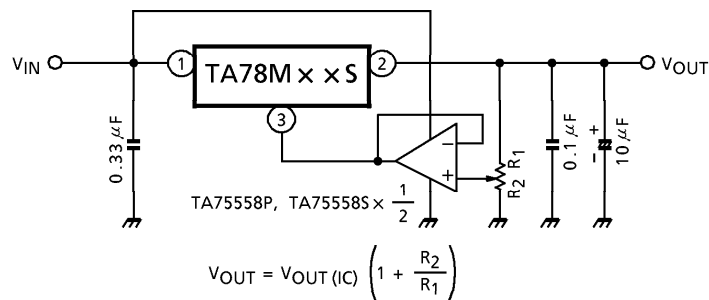
(a) Voltage boost by use of zener diode



(b) Voltage boost by use of resistor

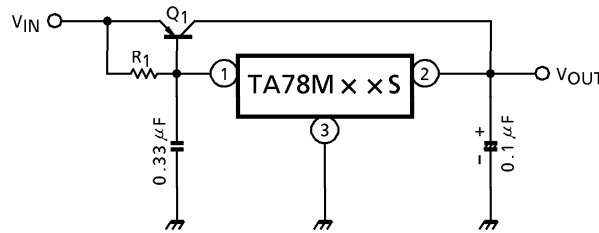


(c) Adjustable output regulator



(2) CURRENT BOOST REGULATOR

(a) CURRENT BOOST VOLTAGE REGULATOR



Heat sink is needed for Q1

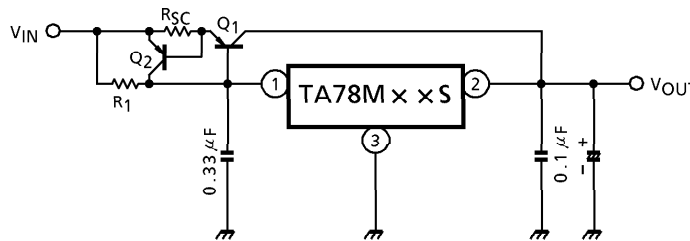
$$R_1 \cong \frac{V_{BE1}}{I_B \text{ MAX}}$$

where,

V_{BE1} : V_{BE} of external transistor Q1.

$I_B \text{ MAX}$: Quiescent current of IC.

(b) SHORT-CIRCUIT PROTECTION

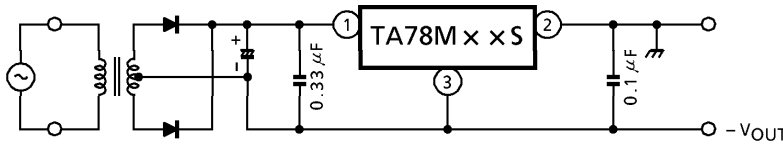


$$R_{SC} = \frac{V_{BE2}}{I_{SC}}$$

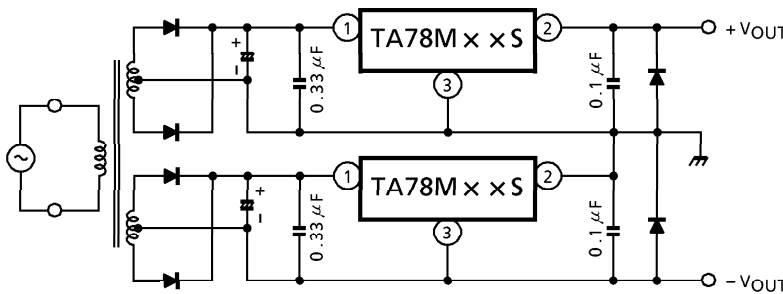
where,

I_{SC} : Short-circuit current

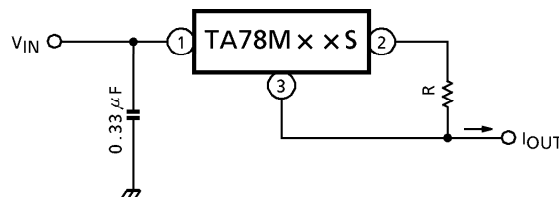
(3) NEGATIVE REGULATOR



(4) POSITIVE AND NEGATIVE REGULATOR



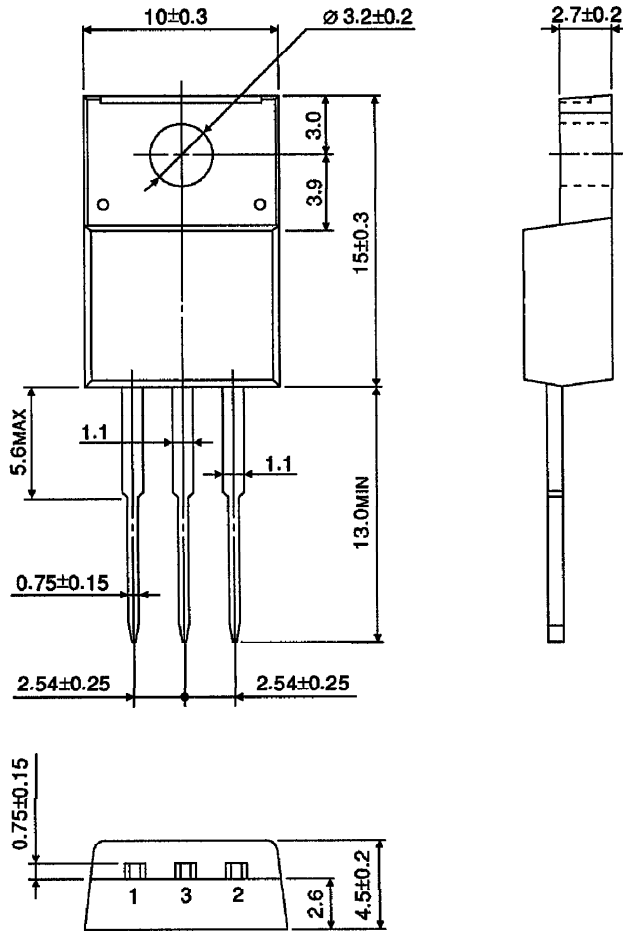
(5) CURRENT REGULATOR



$$I_{OUT} = \frac{V_{OUT}}{R} + I_B$$

PACKAGE DIMENSIONS
P-HSIP3-2.54A

Unit : mm



Weight : 1.7 g (Typ.)